

2, 4 OR 8-CHANNEL, 5-VOLT,

THIN-FILM HEAD, READ/WRITE PREAMPLIFIER

PRELIMINARY

July, 1993

FEATURES

- High Performance
 - Read Gain = 300 V/V Typical
 - Input Noise = 0.65nV/√Hz max
 - Head Inductance Range = 0.2 5 µH
 - Write Current Range 1 40 mA
 - Input Capacitance = 33 pF max
- Differential Pseudo ECL Write Data Input
- Very Low Power Dissipation = 3 mW Typical in Sleep Mode
- Power Up/Down Data Protect Circuitry
- Reduced Write-to-Read Recovery Time
- Single Power Supply = 5 V ± 10%
- Fault Detect Capability
- Designed for 2-Terminal Thin-Film or MIG Heads
- Standard Schottky Isolated 400 Ω Damping Resistor (patent pending)
- Non-Damping Resistor Version Available
- Other Read Gain Options Available
- Available in 2, 4 or 8-Channels

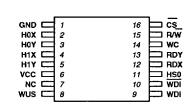
DESCRIPTION

The VM7140 is a high-performance, very low-power read/ write preamplifier designed for use with external 2-terminal, thin-film or MIG recording heads with differential pseudo ECL write data Input. This circuit will operate on a single 5-volt power supply and is ideally suited for use in battery powered disk drives.

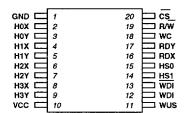
The VM7140 provides write current switching in the write mode and provides a low noise data path in the read mode for up to eight read/write recording heads. When deactivated, the device enters a sleep mode that reduces power dissipation to 3 mW. Data protection circuitry is provided to ensure that the write current source is totally disabled during power supply power up/power down conditions. Write-to-read recovery time is minimized by eliminating common mode output voltage swings when switching between modes.

The VM7140 is available in several different packages. Please consult VTC for package availability and additional read mode voltage gains.

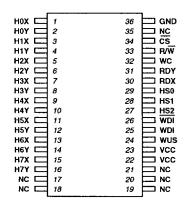
CONNECTION DIAGRAMS



2-Channel 16-lead SOIC

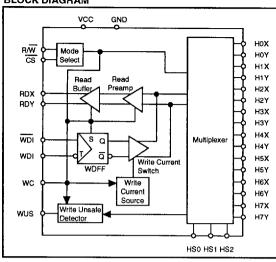


4-Channel 20-lead SOIC, SSOP, VSOP



8-Channel 36-lead SOIC

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

RECOMMENDED OPERATING CONDITIONS

Power Supply Voltage:	
V _{CC}	+5V ± 10%
Write current (I _W)	1 to 40mA
Head Inductance (LH)	
Junction Temperature (T _J)	

CIRCUIT OPERATION

The VM7140 addresses up to four 2-terminal, thin-film recording heads, providing switched write current in the write mode, or data amplification in the read mode. Head selection and mode control is determined by the head select lines, HS1, HS2 and mode control lines, CS, RW as shown in Tables 1 and 2. Internal resistor pullups, provided on the CS and R/W lines, will force the device into a non-write condition if either control line opens up. The part's operation over a wide range of inductive loads makes it suitable for 2-terminal MIG heads.

Write Mode

In write mode, the VM7140 acts as a write current switch with the write unsafe (WUS) detection circuitry activated. Write current is toggled between the X and Y side of the selected head on each high to low transition on the Write Data Flip-Flop (WDFF) so that upon switching to the write mode, the write current flows into the "X" side of the head.

The write current magnitude is determined by an external resistor (RWC) connected between the WC pin and Ground. An internally generated reference voltage is present at the WC pin. The magnitude of the Write Current (0-PK, \pm 8%) is:

$$I_W = K_W/R_{WC} + 0.2mA$$

= 50/R_{WC} + 0.2mA

Power supply fault protection ensures data security on the disk by disabling the write current source during a power supply voltage fault or by supply power up/down conditions. Additionally, the write unsafe (WUS) detection circuitry will flag any of the conditions listed below, as a high level on the WUS line. Two negative transitions on the WDI pin, after the fault is corrected, is required to clear the WUS line.

- · No write current
- WDI frequency too low
- Read or sleep mode

Read Mode

In read mode, the VM7140 acts as a low noise differential amplifier for signals coming off the disk. The write current generator and write unsafe circuitry is deactivated. The RDX, RDY pins are emitter follower outputs and are in phase with "X" and "Y" head ports. These outputs should be AC coupled to the load. The RDX, RDY common mode output voltage is constant, minimizing the transient between read and write mode, thereby, substantially reducing the recovery time in the Pulse Detector circuit connected to these outputs.

Sleep Mode

When CS is high, initially all circuitry is shut down so that power dissipation is reduced to 3 mW in the *Sleep Mode*. Switching the CS line low *wakes up* the chip and the device will enter the read or write mode, depending on the status of the R/W line.

Diode Connected Damping Resistor (patent pending)

The VM7140 has damping resistors isolated by Schottky diodes as an option. The diodes effectively remove the resistor from the circuit during the read mode, however during the write mode with the higher level input signal, the resistor provides damping for the write current waveform.

Input Structure:

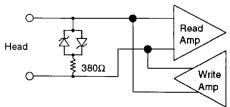


Table 1: Head Select

HS2	HS1	HS0	HEAD
0	0	0	0
0	0	1	1
0	1	0	2
0	1	1	3

Table 2: Mode Select

c s	R/W	MODE
0	0	Write/Awake
0	1	Read/Awake
1	Х	Sleep

PIN DESCRIPTIONS

NAME	νo	DESCRIPTION
HS0-HS2	l*	Head Select: selects one of up to 8 heads
H0X-H7X H0Y-H7Y	1/0	X, Y Head terminals
WDI, WDI	l*	Write Data Input: PECL input signal, negative transition toggles direction of head current
cs	ı	Chip select: high level signal puts chip in sleep mode, low level wakes chip up
R/W	l*	Read/Write select: High level selects read mode, low-level selects write mode
wus	O*	Write unsafe: Open collector output: high level indicates writes unsafe condition
wc	:	Write current adjust: A resistor adjusts level of write current
RDX-RDY	O*	Read data output: differential output data
vcc		+5 volt supply**
GND		Ground

* May be wire-OR'ed for multi-chip usage.

WRITE CHARACTERISTICS Recommended operating conditions apply unless otherwise specified; $L_H = 1 \mu H$, $R_H = 30 \Omega$, $I_W = 20$ mA, $f_{DATA} = 5$ MHz.

PARAMETER	SYM	CONDITIONS	MIN	TYP (Note 1)	MAX	UNITS
WC Pin Voltage	Vwc			2.5		٧
IWC to Head Current Gain	ΑĮ			20		mA/mA
Write Current Constant	Kw	KW = (VWC)(AI)	46	50	54	>
Write Current Range	lw	1.258K < R _{WC} < 60kΩ	1		40	mA
Write Current Tolerance	ΔlW	IW = 10 - 40mA	-8	-1	+8	%
Differential Head Voltage Swing	VDH		4.5	5.4		Vp-p
WDI Transition Frequency for Safe Condition	fDATA	WUS = low	1		l	MHz
Differential Output Capacitance	co				15	рF
Differential Output Resistance	RO		3200			Ω
Unselected Head Transient Current	luн	IW = 15mA		0.15	1	mA(pk)
RDX, RDY Common Mode Output Voltage	V _{СМ}			V _{CC} -2.7		٧

Note 1: Typical values are given at $V_{CC} = 5V$ and $T_A = 25^{\circ}C$.

^{**} Although both VCC connections are recommended, only one connection is required as both are connected internally.

DC CHARACTERISTICS Recommended operating conditions apply unless otherwise specified.

PARAMETER	SYM	CONDITIONS	MIN	TYP (Note 1)	MAX	UNITS
		Read Mode		34 + .05 lW	51 + .05 lW	
Supply Current	lcc	Write Mode		44 + 1.05 lW	52 + 1.05 lW	mA
		ldle Mode		0.6	3	
		Read Mode, I _W = 20mA		165	286	
Power Dissipation	PD	Write Mode, I _W = 20mA		320	402	mW
		ldle Mode		3	17	
Input High Voltage	ViH		2		V _{CC} +0.3	٧
Input Low Voltage	VIL		-0.3		0.8	٧
WDI, WDI Input High Voltage	ViH	Psudeo ECL	V _{CC} -1.0		V _{CC} -0.7	٧
WDI, WDI Input Low Voltage	VIL	Psudeo ECL	V _{CC} -1.9		V _{CC} -1.6	v
Input High Current	ЧΗ	V _{IH} = 2.7V			80	μА
Input Low Current	اال	V _{IL} = 0.4V	-160			μА
WDI, WDI Input High Current	ΊΗ	,			100	μА
WDI, WDI Input Low Current	111			1	80	μА
WUS Output Low Voltage	VoL	I _{OL} = 4.0mA		0.35	0.5	٧
WUS Output High Current	ЮН	V _{OH} = 5.0V		13	100	μА
VCC Value for Write Current Turn Off		l _H < 0.2mA	3.7	4.0	4.3	٧

Note 1: Typical values are given at $V_{CC} = 5V$ and $T_A = 25$ °C.

VM7140

READ CHARACTERISTICS Recommended operating conditions apply unless otherwise specified; C_L (RDX, RDY) < 20pF, R_L (RDX, RDY) = 1k Ω .

PARAMETER	SYM	CONDITIONS	MIN	TYP (Note 1)	MAX	UNITS	
Differential Voltage Gain	Αγ	V _{IN} = 1mVrms, 1MHz; Note 2 120 150		180	V/V		
		-1dB Zs < 5Ω, V _{IN} = 1mVp-p	40	55	55		
Bandwidth	BW -3	-3dB Zs < 5Ω, V _{IN} = 1mVp-p	65	85		MHz	
Input Noise Voltage	e _{in}	BW = 17MHz, $L_H = 0$, $R_H = 0$		0.5	0.7	nV/√Hz	
Differential Input Capacitance	CIN	V _{IN} = 1mVp-p, f = 5MHz		33	45	pF	
Differential Input Resistance	RiN	V _{IN} = 1mVp-p, f = 5MHz	380	1000		Ω	
Dynamic Range	DR	AC input where Ay is 90% of gain at 0.2mVrms input	2	5		mVrms	
Common Mode Rejection Ratio	CMRR	V _{IN} = 100mVp-p @5MHz	50	70		dB	
Power Supply Rejection Ratio	PSRR	100mVp-p @5MHz on VCC	45	66		dB	
Channel Separation	CS	Unselected channel driven with 20mVp-p @5MHz	40	45		dB	
Output Offset Voltage	Vos		-300	2	+300	mV	
RDX,RDY Common Mode Output Voltage	Vосм	Read Mode		V _{CC} -2.7		٧	
Read to Write Common Mode Output Voltage Difference	∆∨осм		-350	-45	350	mV	
Single-Ended Output Resistance	RSEO			22	35	Ω	
Output Current	Ю	AC Coupled Load, RDX to RDY	±1.5			mA	

Note 1: Typical values are given at V_{CC} = 5V and T_A = 25°C. Note 2: A_V is mask programmable for nomial values of: 150 and 300V/V.

VM7140

SWITCHING CHARACTERISTICS Recommended operating conditions apply unless otherwise specified; I_W = 20mA, f_{DATA} = 5MHz, L_H = 1 μ H, R_H = 30 Ω , C_L (RDX, RDY) \leq 20pF (see Figure 1).

PARAMETER	SYM	CONDITIONS		MIN	TYP (Note 1)	MAX	UNITS
R/W Read to Write Delay	tRW	R/W to 90% IW	R/W to 90% IW		0.06	1.0	μs
R/W Write to Read Delay	twR	R/W to 90% of 100n envelope	R/W to 90% of 100mV, 10MHz read signal envelope		0.15	1.0	μs
CS Unselect to Select Delay	tIR		CS to 90% IW or 90% of 100mV, 10MHz read signal envelope		0.23	0.6	μs
CS Select to Unselect Delay	tRI	CS to 10% of IW			0.02	0.6	μs
HS0, 1, any Head Delay	tHS	HS0, 1 to 90% of 100mV, 10MHz read signal envelope			0.23	0.6	μs
WUS Safe to Unsafe Delay	t _{D1}			0.6	2.1	3.6	μs
WUS Unsafe to Safe Delay	t _{D2}					1.0	μs
Head Current Propagation Delay (TD3)	tDЗ	L _H = 0, R _H = 0, from 50% points			12	30	ns
Head Current Asymmetry	ASYM	50% duty cycle on WDI, 1ns rise/fall time; LH = 0, RH = 0			0.04	0.5	ns
	. /*-	100/ 4- 000/	LH = 0, RH = 0		2	5	ns
Head Current Rise/Fall Time	t _r /t _f	10% to 90% points	L _H = 1μH, R _H = 30Ω		12	16] ,,,,

Note 1: Typical values are given at V_{CC} = 5V and T_A = 25°C.

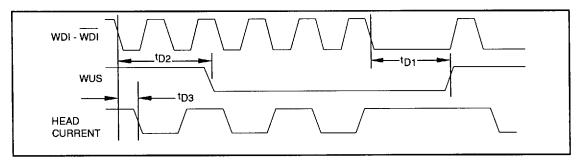


Figure 1: Write Mode Timing Diagram